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Mechanical and electronic properties of vanadium oxide nanotubes

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DOI: <https://doi.org/10.1063/1.3103280>

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Journal Article

Published Version

Originally published at:

Sipos, B; Duchamp, M; Magrez, A; Forró, L; Barišić, N; Kis, A; Seo, J W; Bieri, F; Krumeich, F; Nesper, R; Patzke, Greta R (2009). Mechanical and electronic properties of vanadium oxide nanotubes. *Journal of Applied Physics*, 105(7):074317.

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Citation: *Journal of Applied Physics* **105**, 074317 (2009); doi: 10.1063/1.3103280

View online: <http://dx.doi.org/10.1063/1.3103280>

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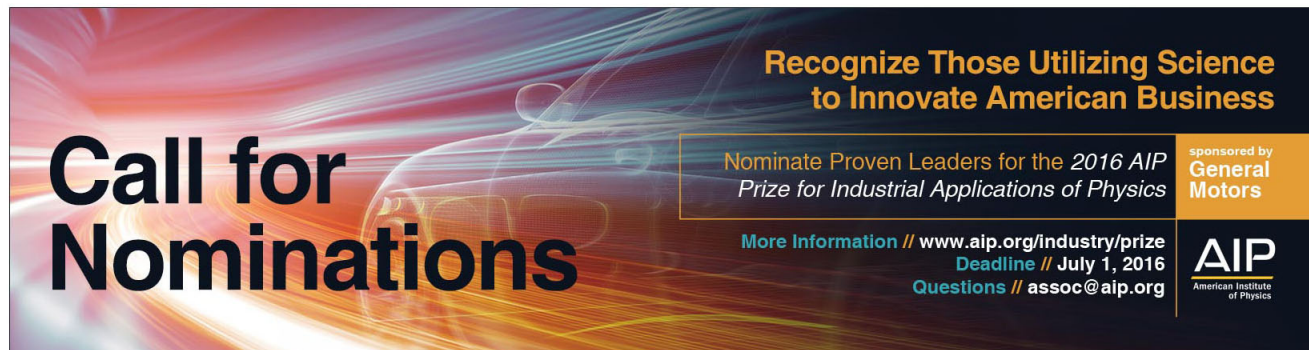
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Mechanical and electronic properties of vanadium oxide nanotubes

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(Received 24 November 2008; accepted 17 February 2009; published online 14 April 2009)

Vanadium oxide nanotubes with a diameter of 20–100 nm and an aspect ratio of 50–100 were synthesized by hydrothermal method. Young's modulus of 20–80 GPa was obtained by bending measurements of individual nanotubes using an atomic force microscope. Electrical resistivity and thermopower measurements on a large assembly of nanotubes determined the characteristic energies required to put a charge into a polaronic site ($\Delta E_g = 0.20$ eV) and to extract and propagate the polaron between neighboring sites ($\Delta E_p = 0.09$ eV). © 2009 American Institute of Physics. [DOI: 10.1063/1.3103280]

I. INTRODUCTION

Since the discovery of carbon nanotubes, quasi-one-dimensional materials have attracted great interest because of their remarkable properties and a wide range of significant technological implications.¹ Unfortunately, carbon nanotubes exist in different chiralities and diameters, corresponding to metallic or semiconducting tubes. Although some control over the tube diameter has been achieved during synthesis on patterned substrates, the state of the art carbon nanotube growth does not yet allow obtaining tubes of one specific type. Therefore, nanostructures that are more uniform in structure and in electronic properties are of importance. Possible alternatives include nanotubes, nanowires, nanorods, and nanoribbons of various elements and compounds that have been synthesized meanwhile.² Especially, nanotubes of transition metal oxides represent a unique class of materials because of the variable oxidation state of the transition metal, which is connected with interesting electrochemical and physical properties.³

Vanadium oxide (VO_x) is a system that forms nanotubes as well as nanowires.⁴ The tube walls consist of bent VO_x layers between which organic molecules are embedded. The VO_x layers are crystalline with planar unit cell of V_7O_{16} (Ref. 5) containing two sheets of edge-sharing pentagonal pyramids coupled in zigzag chains. These sheets are connected via VO_4 tetrahedra. In this structure, mixed valency of V ions occurs (V^{4+} and V^{5+}) and contributes to the electronic conductivity. The relative V^{4+} content was calculated to about 46% yielding a valency of about 4.54+.⁴ From x-ray photoelectron spectroscopy and electron energy loss spec-

troscopy (EELS) measurements a nonzero occupation of the V 3d shell was observed,⁶ and the averaged vanadium valency was determined to be 4.4+.

Recently, nanotubes of VO_x have attracted much attention because Krusin-Elbaum *et al.*⁷ reported that the as-formed VO_x nanotubes can be transformed from spin-frustrated semiconductor to ferromagnet by doping with either electrons (Li) or holes (I), yielding room-temperature ferromagnetic material for spintronic applications. Nevertheless, pristine VO_x nanotubes are also attractive for lithium batteries⁸ and thermochromic applications;⁹ they are good gas sensors with extremely high sensitivity and selectivity,¹⁰ optical limiters¹¹ in the visible and infrared spectral ranges, etc. The simple and low-cost synthesis procedure involving soft chemistry is also an advantage for this material.¹² These features show that VO_x is a promising functional material; hence it is important to explore its physical properties in both forms, i.e., the properties of individual tubes and that of large arrays. Therefore, in this contribution, we report on the mechanical and electronic properties of VO_x nanotubes.

II. EXPERIMENTAL DETAILS

The VO_x nanotubes were prepared using a hydrothermal procedure described in detail in previous works.^{3,4} As V_2O_5 is a nonstoichiometric compound because of oxygen vacancies, we use the notation VO_x , but $\text{V}_2\text{O}_{5-\delta}$ would be equally good. Figure 1 shows a representative transmission electron micrograph of VO_x nanotubes used in this study. The length of the tubes varied between 1 and 10 μm while the diameter was in the 20–100 nm range. As found by transmission electron microscopy (TEM), the tubes were open ended. It has to be mentioned that the VO_x tubes are not perfect cylinders but scrolls made from a single VO_x sheet. Detailed TEM investigations revealed that VO_x forms concentric layers as well

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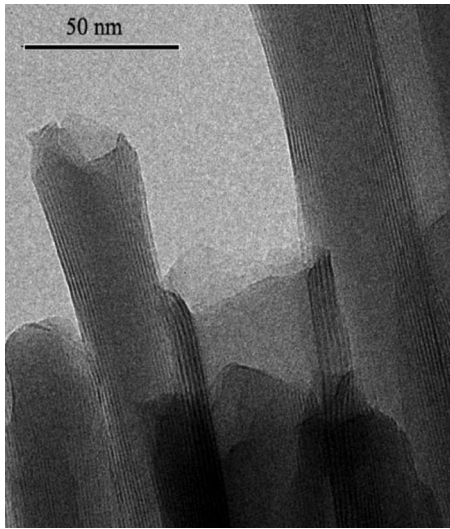


FIG. 1. Representative TEM image of VO_x nanotubes used in the present study. The walls around the empty core are visible as well as that the tubes are open ended.

as scrolls.^{4,13} Most tubes are disordered variants of the pure forms. Actually, the synthesis involves the use of amines without which no tubes are formed. The length of the VO_x tubes increases with the alkyl chain of the amine. It was found that amine molecules are intercalated within the scroll structure in-between the tubes. This structural characterization corroborates with previous studies.^{6,11}

For the transport and thermoelectric power (Seebeck-coefficient) measurements, we have produced a VO_x nanotube film by drawing a tube suspension through a $0.2\ \mu\text{m}$ pore ceramic filter, which left a uniform grayish/black deposit on the filter. The residue of randomly oriented VO_x nanotubes was about 1 mm thick and it was subsequently vacuum dried. Rectangular-shape samples with a typical size of $8.0 \times 5.0\ \text{mm}^2$ were cut out from the deposit and used for measurements.

The resistivity was measured in a conventional four-probe configuration. Gold-wire electrodes were attached to the sample by using a silver paste. Its temperature dependence was measured in the 160–800 K temperature range. To perform the thermoelectric power measurement the sample was mounted on a ceramic sample holder, whereupon miniaturized heaters were attached to both ends for generating a temperature gradient which was measured with a differential K-type thermocouple. A typical temperature difference was 1 K.

For the measurement of the elastic property, individual VO_x nanowires were used. We applied the technique developed in our group by Salvétat *et al.*¹⁴ for the measurements of carbon nanotubes. The nanotubes were dispersed in ethanol by sonication, and their dispersion was placed over alumina or Si_3N_4 membranes. Occasionally nanotubes lie over a hole with a short section of their entire length, whereas the major part of the nanotube is still in contact with the membrane surface and therefore can be considered as clamped by van der Waals forces [see Fig. 2(a)]. By means of an atomic force microscope (AFM), changes in the vertical deflection (δ) are measured as a function of the nominal applied force

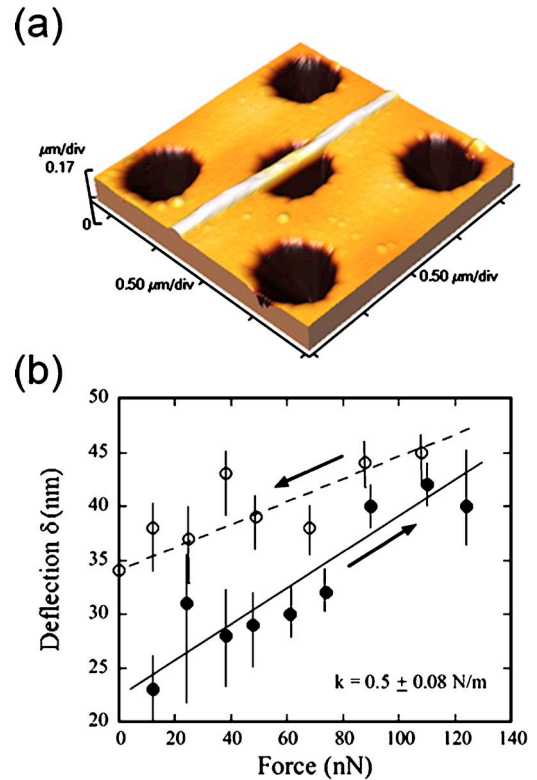


FIG. 2. (Color online) (a) AFM image of a VO_x nanotube adhered to the Si_3N_4 membrane with a portion bridging a pore of 500 nm of the membrane. (b) Nanotube deflection vs applied force for loading (full dots) and unloading (empty dots). The residual deflection is due to permanent deformation. The spring constant k of the cantilever is also given.

(F), which is inversely proportional to Young's modulus of the nanotube. Using simple beam mechanics, Young's modulus (E) is expressed as $E = FL^3 / \delta \alpha I$, where $\alpha = 192$ for a clamped beam, F is the applied force varying from image to image, $I = \pi(D^4 - D_i^4) / 64$ is the moment of inertia, and D_i is the inner radius of a tube. The height of the nanotube is derived from a part that lies on the flat membrane surface and is set equal to the diameter D . For the suspended length L we take the pore width on sites just next to the nanotube. The systematic error mainly originates from the uncertainty in L . Note that the lack of knowing the inner diameter (D_i) of the measured tube introduces a minor error in the absolute value due to its fourth power in the expression of E . Calculation of E is based on the assumption that the nanotube is perfectly clamped to the membrane. Adhesion depends on the real contact surface between the nanotube and the substrate, and if the contact surface is small (either due to the bent structure of the tube or to a nonflat surface) the nanotube can move. This situation can be screened by taking subsequent images of the nanotube/membrane assembly. In the data presented here, the nanotubes were firmly clamped to the surface.

III. RESULTS AND DISCUSSION

A typical force-deflection curve for loading and unloading is shown in Fig. 2(b). Every point corresponds to a scanning of the nanotube/membrane in contact mode with a constant force. On subsequent scans the position of the nanotube

TABLE I. Summary of the AFM measurements.

Tube No.	Diameter (nm)	Suspended length (nm)	Young's modulus (GPa)	Substrate
1	18.5	316	80 ± 40	Al_2O_3
2	36	666	30 ± 15	Si_3N_4
3	36	700	20 ± 10	Si_3N_4

was the same (thus, no sliding on the membrane surface); only its deflection increased over the hole. The slope of δ versus F is inversely proportional to Young's modulus of the nanotube (see the expression above). In many cases the slope of the first loading curve is significantly higher than the unloading one. In our interpretation this is due to presence of the amine groups in-between the layers. These organic molecules render the mechanical response softer until they are squeezed by the increasing load. Coming back from the highest load, the nanotube gives a more intrinsic, higher modulus. Due to this phenomenon, the measured values of Young's modulus span the 20–80 GPa range but we believe that the higher values are more intrinsic to the VO_x layers. Selected measurements with all the important parameters are listed in Table I.

How do these values compare to Young's modulus reported on other forms of vanadium pentoxide? The most common phase is the $\alpha\text{-V}_2\text{O}_5$ which is built up from VO_5 square pyramids shearing edges and corners which build up layers. The V_2O_5 layers are held together by weak, van der Waals type V–O interactions. Due to this architecture of the lattice, the mechanical response is very anisotropic. The modulus in one direction could be as high as 220 GPa, while it cleaves¹⁵ very easily along the (001) planes at that point that V_2O_5 is foreseen to be a promising solid lubricant.¹⁶ This is very similar to the case of graphite, which has a high in-plane modulus but low shear modulus between the planes. By rolling up the graphite sheets as carbon nanotubes, the low shear modulus is eliminated. A similar effect is expected for VO_x tubes: Rolling up the V_2O_5 layers one should approach the high modulus measured for single crystals. The fact that the measured values are low is due to defects in the tubes. Already for single crystals Jachmann and Hucho¹⁵ showed that the elastic modulus is very sensitive to the stoichiometry of the compound. Fateh *et al.*¹⁷ reported that with the increase in the crystallinity of the thin films of V_2O_5 , Young's modulus can increase from 80 to 130 GPa.

Young's modulus of the VO_x nanotubes presented here is far from that of single crystals or well-ordered thin films. Although the structure is crystalline at a local scale, it is less ordered on a long range as TEM analysis revealed. This could be due to the low temperature synthesis of the nanotubes and/or to the oxygen deficiency in the structure. These combined effects make the overall mechanical response weak. In many nanostructures (nanotubes and nanowires) significantly lower Young's modulus compared to the bulk value has been observed, originating from different levels of defects and variance in their synthesis conditions. In the case of carbon nanotubes, the value of Young's modulus is assumed to be around 1 TPa for multi- and single-walled car-

bon nanotubes grown by arc-discharge and laser ablation methods whereas carbon nanotubes produced by catalytic chemical vapor deposition show Young's modulus lower than 100 GPa.^{18,19} Similar effects have been observed for ZnO nanowires with Young's modulus of about 100 GPa, which is 30% lower than the bulk value.²⁰ For VO_x nanotubes, although p and n doping may render the nanotubes ferromagnetic⁷ and make them very promising for spin dependent scanning probe applications, the structural perfectness of these tubes has to be improved. In particular, for Li-doped nanotubes, Hellmann *et al.*²¹ recently indicated that the structural instability is a major concern. Although the charge transfer upon doping could be confirmed by EELS, the tubes were strongly electron beam sensitive, indicating a metastable structure. Moreover, the Li doping was found to disappear upon short exposure to air. This phenomenon was explained by the preferential diffusion of Li ions to the sample surface and by the formation of Li oxide or hydroxide.

Extended structural defects can influence the dc electrical conductivity as well. Indeed, resistivity measurements on individual VO_x nanotubes gave a substantial scattering in the absolute value at 300 K in the range of 10^3 – 10^5 Ω cm (not shown). This large dispersion might be due to extended defects in the structure of the tubes, maybe related to the amine groups in-between the layer, and/or to the difference in oxygen off-stoichiometry of different nanotubes. In many applications, a large assembly of nanotubes is more attractive than individual nanotubes, in particular, because of the easier handling. Transport measurement on such assembly shows higher reproducibility. It seems that the more conducting tubes (or parts of the tubes) form a good percolative network. The room-temperature value of resistivity is in the range of 200 Ω cm.

Band structure calculations²² and optical absorption measurements²³ of V_2O_5 revealed a band-gap energy of 2.4–2.7 eV. However, when one plots the logarithm of resistivity as $1/T$, the activation energy is much less than that; it is in the 0.2–0.4 eV range, pointing toward a low-lying impurity level.^{24,25} Indeed, it is considered that vanadium pentoxide (in any forms) is always oxygen deficient, and oxygen vacancies are contributing to the electronic conductivity in the following way: The vacancies are compensated by excess electrons located on vanadium sites, reducing V^{5+} to V^{4+} . In this way, the unpaired electron is localized on two vanadium sites associated with an oxygen vacancy. As electron spin resonance (ESR) and dc conductivity measurements on V_2O_5 single crystals revealed, the localized charge deforms the lattice in its vicinity leading to the formation of small polarons.²⁶ These measurements revealed an activation energy of about 0.1 eV at low temperature (below 160 K) in contrast to 0.2 eV at high temperature. Unfortunately, data on VO_x nanotubes are limited. However, ESR measurements on VO_x nanotubes showed similar features to those of V_2O_5 single crystals but the inhomogeneous distribution of V^{4+} was found to increase even more after the hydrothermal treatment.²⁷

How these polarons carry current and heat can be derived from the electrical resistivity and thermoelectric power

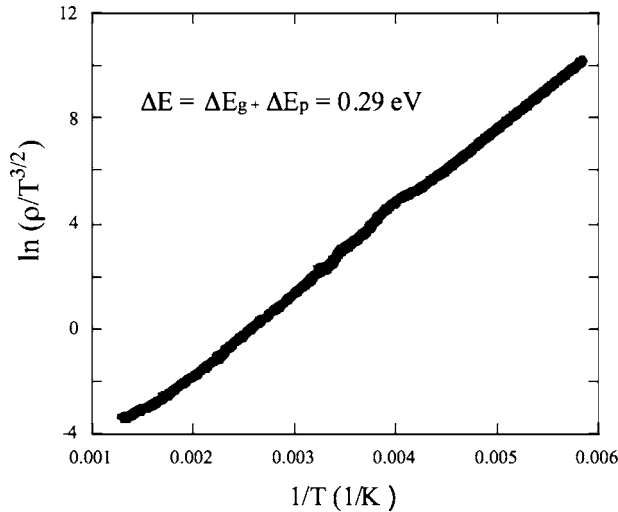


FIG. 3. In order to stress the hopping nature of electrical conduction in VO_x nanotubes, the electrical resistivity is plotted as $\ln(\rho/T^{3/2})$ vs $1/T$ for a thick film sample.

measurements. The temperature dependence of the dc resistivity of the nanotubes in a nonadiabatic hopping conductivity can thus be expressed by the formula²⁸

$$\rho = AT^{3/2} \exp(\Delta E/kT), \quad (1)$$

where ΔE is the activation energy of the conductivity. It can be decomposed into the energies ΔE_g and ΔE_p . The first term corresponds to an energy required to put a charge into a polaronic site whereas the second term describes the energy necessary to extract the charge from its polaronic cloud and to propagate it between neighboring sites. These two contributions could be separated if one measures the thermoelectric (Seebeck) coefficient (S). When the conduction happens through hopping of polarons between localized states, although the rate is governed by ΔE_p , it does not represent an additional energy gain because the initial and final states have the same energy. Hence, S is determined only by the configurational entropy of these polarons and it gives a temperature independent contribution $(k_B/e)\ln \rho$ (where ρ is the density of charge carriers per site). But if the charges have to be thermally activated into the polaronic state,²⁹ similar to the case of a band semiconductor, then S is

$$S \sim k_B/e(\Delta E_g/2k_B T). \quad (2)$$

The resistivity measured in a broad temperature range gives a reasonably good agreement with expression (1) for a nonadiabatic hopping (see Fig. 3). This expression differs from a simple semiconducting activation by the prefactor $T^{3/2}$ which comes from the temperature dependence of the hopping frequency of polarons. This term gives a better fit for the data points above 300 K in Fig. 3. The thermopower data in Fig. 4 follow expression (2), clearly demonstrating that the charge carriers are thermally activated into the polaronic sites. Furthermore, the sign of the Seebeck coefficient indicates predominantly p -type conduction. With simple arithmetics we obtain $\Delta E_g = 0.2$ eV and $\Delta E_p = 0.09$ eV energies. This is a reasonable value for polaron binding energy, comparable to 0.1 eV found in manganites.³⁰

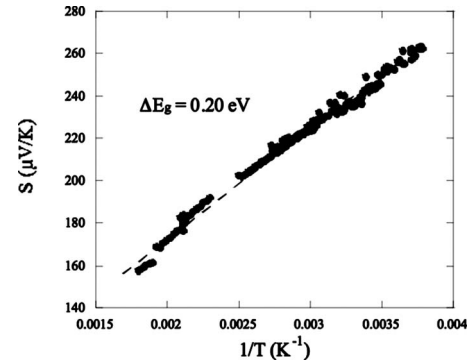


FIG. 4. Thermoelectric power vs inverse temperature measured for a thick film of VO_x nanotubes. The slope gives the activation energy needed for putting charges into the polaronic state.

IV. CONCLUSIONS

In conclusion, Young's modulus of individual VO_x nanotubes was successfully measured using an AFM technique. E is below 100 GPa, which is lower than expected from the bulk value. This is presumably due to the structural defects caused by oxygen vacancies. These vacancies dope the nanotubes, and the charge carriers have a polaronic character. Our electrical resistivity and thermoelectric power measurements revealed that in a macroscopic assembly of nanotubes, the tube-tube contact is good, and despite its porous nature the sample has a reasonable conductance of 0.005 S/cm. Such a value in combination with respect to their extraordinary structure is promising for battery applications.³¹

ACKNOWLEDGMENTS

This work was supported by the Swiss National Science Foundation and its NCCR Materials with Novel Electronic Properties (MaNEP).

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